

# LM148/LM248/LM348 Quad 741 Op Amps

## General Description

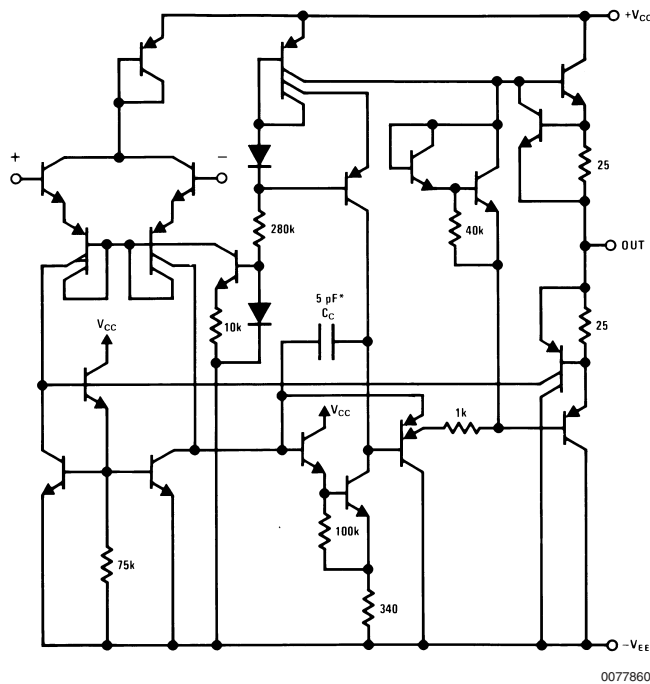
The LM148 series is a true quad 741. It consists of four independent, high gain, internally compensated, low power operational amplifiers which have been designed to provide functional characteristics identical to those of the familiar 741 operational amplifier. In addition the total supply current for all four amplifiers is comparable to the supply current of a single 741 type op amp. Other features include input offset currents and input bias current which are much less than those of a standard 741. Also, excellent isolation between amplifiers has been achieved by independently biasing each amplifier and using layout techniques which minimize thermal coupling.

The LM148 can be used anywhere multiple 741 or 1558 type amplifiers are being used and in applications where amplifier matching or high packing density is required. For lower power refer to LF444.

## Features

- 741 op amp operating characteristics
- Class AB output stage—no crossover distortion
- Pin compatible with the LM124
- Overload protection for inputs and outputs
- Low supply current drain: 0.6 mA/Amplifier
- Low input offset voltage: 1 mV
- Low input offset current: 4 nA
- Low input bias current: 30 nA
- High degree of isolation between amplifiers: 120 dB
- Gain bandwidth product
- LM148 (unity gain): 1.0 MHz

## Schematic Diagram



\* 1 pF in the LM149

**Absolute Maximum Ratings** (Note 4)

Distributors for availability and specifications.

If Military/Aerospace specified devices are required,  
please contact the National Semiconductor Sales Office/

	LM148	LM248	LM348
Supply Voltage	±22V	±18V	±18V
Differential Input Voltage	±44V	±36V	±36V
Output Short Circuit Duration (Note 1)	Continuous	Continuous	Continuous
Power Dissipation ( $P_d$ at 25°C) and Thermal Resistance ( $\theta_{JA}$ ), (Note 2)			
Molded DIP (N) $P_d$	—	—	750 mW
$\theta_{JA}$	—	—	100°C/W
Cavity DIP (J) $P_d$	1100 mW	800 mW	700 mW
$\theta_{JA}$	110°C/W	110°C/W	110°C/W
Maximum Junction Temperature ( $T_{JMAX}$ )	150°C	110°C	100°C
Operating Temperature Range	-55°C ≤ $T_A$ ≤ +125°C	-25°C ≤ $T_A$ ≤ +85°C	0°C ≤ $T_A$ ≤ +70°C
Storage Temperature Range	-65°C to +150°C	-65°C to +150°C	-65°C to +150°C
Lead Temperature (Soldering, 10 sec.) Ceramic	300°C	300°C	300°C
Lead Temperature (Soldering, 10 sec.) Plastic			260°C
Soldering Information			
Dual-In-Line Package			
Soldering (10 seconds)	260°C	260°C	260°C
Small Outline Package			
Vapor Phase (60 seconds)	215°C	215°C	215°C
Infrared (15 seconds)	220°C	220°C	220°C
See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.			
ESD tolerance (Note 5)	500V	500V	500V

**Electrical Characteristics**

(Note 3)

Parameter	Conditions	LM148			LM248			LM348			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	$T_A = 25^\circ\text{C}$ , $R_S \leq 10\text{ k}\Omega$		1.0	5.0		1.0	6.0		1.0	6.0	mV
Input Offset Current	$T_A = 25^\circ\text{C}$		4	25		4	50		4	50	nA
Input Bias Current	$T_A = 25^\circ\text{C}$		30	100		30	200		30	200	nA
Input Resistance	$T_A = 25^\circ\text{C}$	0.8	2.5		0.8	2.5		0.8	2.5		MΩ
Supply Current All Amplifiers	$T_A = 25^\circ\text{C}$ , $V_S = \pm 15\text{V}$		2.4	3.6		2.4	4.5		2.4	4.5	mA
Large Signal Voltage Gain	$T_A = 25^\circ\text{C}$ , $V_S = \pm 15\text{V}$ $V_{OUT} = \pm 10\text{V}$ , $R_L \geq 2\text{ k}\Omega$	50	160		25	160		25	160		V/mV
Amplifier to Amplifier Coupling	$T_A = 25^\circ\text{C}$ , $f = 1\text{ Hz to } 20\text{ kHz}$ (Input Referred) See Crosstalk Test Circuit		-120			-120			-120		dB
Small Signal Bandwidth	$T_A = 25^\circ\text{C}$ , LM148 Series		1.0			1.0			1.0		MHz
Phase Margin	$T_A = 25^\circ\text{C}$ , LM148 Series ( $A_V = 1$ )		60			60			60		degrees
Slew Rate	$T_A = 25^\circ\text{C}$ , LM148 Series ( $A_V = 1$ )		0.5			0.5			0.5		V/μs
Output Short Circuit Current	$T_A = 25^\circ\text{C}$		25			25			25		mA
Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$			6.0			7.5			7.5	mV
Input Offset Current				75			125			100	nA

## Electrical Characteristics (Continued)

(Note 3)

Parameter	Conditions	LM148			LM248			LM348			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Bias Current				325			500			400	nA
Large Signal Voltage Gain	$V_S = \pm 15V$ , $V_{OUT} = \pm 10V$ , $R_L > 2\text{ k}\Omega$	25			15			15			V/mV
Output Voltage Swing	$V_S = \pm 15V$ , $R_L = 10\text{ k}\Omega$ $R_L = 2\text{ k}\Omega$	$\pm 12$	$\pm 13$		$\pm 12$	$\pm 13$		$\pm 12$	$\pm 13$		V
		$\pm 10$	$\pm 12$		$\pm 10$	$\pm 12$		$\pm 10$	$\pm 12$		V
Input Voltage Range	$V_S = \pm 15V$	$\pm 12$			$\pm 12$			$\pm 12$			V
Common-Mode Rejection Ratio	$R_S \leq 10\text{ k}\Omega$	70	90		70	90		70	90		dB
Supply Voltage Rejection	$R_S \leq 10\text{ k}\Omega$ , $\pm 5V \leq V_S \leq \pm 15V$	77	96		77	96		77	96		dB

**Note 1:** Any of the amplifier outputs can be shorted to ground indefinitely; however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.

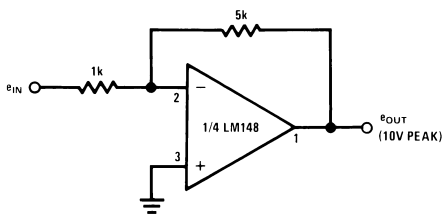
**Note 2:** The maximum power dissipation for these devices must be derated at elevated temperatures and is dictated by  $T_{JMAX}$ ,  $\theta_{JA}$ , and the ambient temperature,  $T_A$ . The maximum available power dissipation at any temperature is  $P_d = (T_{JMAX} - T_A)/\theta_{JA}$  or the 25°C  $P_{DMAX}$ , whichever is less.

**Note 3:** These specifications apply for  $V_S = \pm 15V$  and over the absolute maximum operating temperature range ( $T_L \leq T_A \leq T_H$ ) unless otherwise noted.

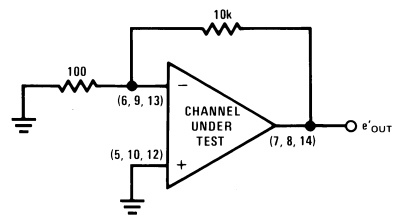
**Note 4:** Refer to RETS 148X for LM148 military specifications.

**Note 5:** Human body model, 1.5 k $\Omega$  in series with 100 pF.

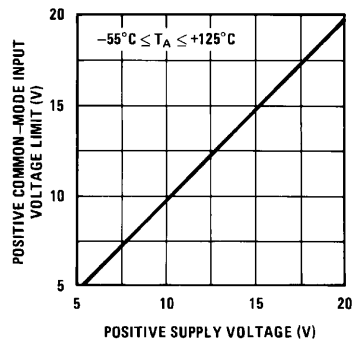
### Cross Talk Test Circuit $V_S = \pm 15V$



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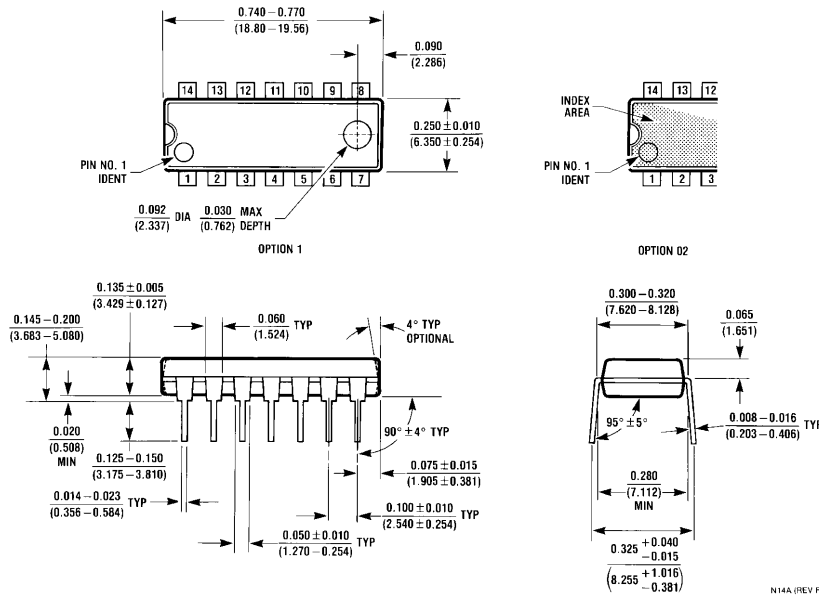
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**Physical Dimensions** inches (millimeters) unless otherwise noted (Continued)



**Molded Dual-In-Line Package (N)**  
**Order Number LM348N**  
**NS Package Number N14A**

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